

# Probing Copper and Copper–Gold Alloy Surfaces with Space-Quantized Oxygen Molecular Beam

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hindered the surface from further oxidation, introducing a higher activation barrier to chemisorption and rendering an almost negligible azimuthal anisotropy. The presence of Au also prevented the cartwheel-like rotations of  $O_2$ .

**KEYWORDS:** metal surface, oxidation, copper, copper–gold alloy, steric effect

# INTRODUCTION

Activation of molecular oxygen ( $O_2$ ) constitutes an important step in oxidative processes, including heterogeneous catalysis, electrocatalysis, and corrosion of metals.<sup>1–7</sup> The interaction of  $O_2$  with various metal surfaces induces changes in its chemical stability and reactivity. It follows that the ability to control such processes bears on the chemical economic world. Alloying of pristine metals provides one of the simplest ways to do so. Understanding the microscopic mechanism behind  $O_2$ chemisorption entails unraveling the stereochemistry of the processes involved.<sup>8–14</sup>

 $O_2$  dissociative adsorption on Cu(110) provides a model system for understanding the oxidation processes on Cu surfaces.<sup>15-32</sup> The pristine Cu(110) surface possesses an anisotropic surface structure, on which anisotropic Cu–O chains grow as a precursor to oxide formation.<sup>28-32</sup> Early molecular beam experiments observed initial sticking probabilities ( $S_0$ ) increasing with translational energy ( $E_t$ ), approaching 0.8 at a high enough  $E_t^{24}$ 

At low  $E_v$  two competing mechanisms could account for the observed O<sub>2</sub> dissociative adsorption. A precursor-mediated channel (a weakly bound, physisorbed *trapping* molecular state) dominates at low  $E_t$  and low surface temperatures ( $T_s$ ). Activated dissociative chemisorption becomes important as  $E_t$  increases, which occurs directly and/or via a *short-lived* molecularly chemisorbed state. One could also think of a

*three-well* potential<sup>33</sup> that ascribes transient molecularly chemisorbed states to negatively ionized  $O_2^-$ , e.g., the peroxo state, as suggested by high-resolution electron energy loss spectroscopy (HREELS) measurements<sup>17,18</sup> and -density functional theory (DFT)-based calculations.<sup>19</sup> Such negatively charged states could account for the high sticking probability and the well-known efficient catalytic activity of Cu for oxidation.

At high  $E_{p}$  hyperthermal molecular oxygen beam (HOMB) experiments<sup>14</sup> report effective formation of Cu<sub>2</sub>O precursor on Cu(110), that exhibits dependence on the azimuthal orientation at which O<sub>2</sub> impinges the surface. This demonstrates another important feature that comes from the inherent orientation dependence of reactions. The stereodynamics of reactant molecules (the orientation and the movement of molecules in 3D space) plays an important role in reactions. The small rotational energy excitations involved (ca. less than a few meV) render the reactants susceptible to dynamical *steering*<sup>1,34–36</sup> and make direct verification of

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**Figure 1.** (Space quantized)  $O_2$  sticking probabilities on Cu(110). (a) Angular distributions (upper panel) of the molecular axis (O–O bond axis) of an  $O_2$  (in the triplet electronic ground state  ${}^{3}\Sigma_{g}^{-}$  and spin-rotational state (J = 2, M = 2)) with respect to Cu(110) (schematically depicted in the lower panel) and corresponding defining magnetic fields  $\vec{\mathcal{H}}$ . Orienting  $\vec{\mathcal{H}}$  perpendicular to the surface, i.e., along  $[\overline{1}\ \overline{1}0]$ , results in helicopter-like rotating  $O_2$ . Two types of cartwheel-like rotating  $O_2$  can also be realized by orientating  $\vec{\mathcal{H}}$  parallel to the surface, i.e., either along  $[\overline{1}10]$  or [001]. (b) Time evolution of the sticking probability for a space-quantized  $O_2$  impinging on Cu(110) (at a surface temperature of ca. 310 K) with translational energy  $E_t = 0.10$  eV. Time t = 0 corresponds to the time the beam shutter is opened to allow the molecular beam to impinge on the surface. Following the control signal shown (topmost right panel), the  $\vec{\mathcal{H}}$  direction can be modulated to alternately produce helicopter-like (high signal) and cartwheel-like (low signal) rotating  $O_2$  that impinge on Cu(110). Numerical fits to the corresponding sticking probability data points (using exponentially decaying functions extrapolated to t = 0) also shown to guide the eye. The values at t = 0 correspond to the initial sticking probabilities  $S_0(H)$ ,  $S_0(C_x)$ , and  $S_0(C_y)$ .

calculated potential energy surfaces (PES) rather challenging.<sup>1,10–14,25,37</sup> Helicopter-like rotating O<sub>2</sub> (with dominant rotational angular momentum J parallel along the surface normal) adsorbs more effectively than cartwheel-like rotating O<sub>2</sub> (with J perpendicular to the surface normal).<sup>19,20,22</sup> As mentioned earlier, a possible candidate for transient molecularly chemisorbed state would be an adsorbed O<sub>2</sub> exhibiting peroxo-like character (O<sub>2</sub><sup>-</sup>), with azimuthal orientationdependent stability.<sup>19,20,22</sup> As expected from previous discussions,<sup>34–36</sup> at high  $E_t$  (ca. 500 meV), the impinging O<sub>2</sub> does not have enough time to reorient (be steered) and the favorable helicopter-like rotating O<sub>2</sub> dominantly account for chemisorption.<sup>19</sup> On the other hand, at low  $E_t$  (ca. 50 meV), the impinging O<sub>2</sub> have enough time to reorient (be steered) to more favorable orientations toward reactive sites.<sup>19</sup>

Ancient people know that alloying with inert gold (Au) protects Cu from further corrosion, and we observe several ancient products enduring in rather pristine condition.<sup>38</sup> Now, we know that the deeper *d*-band center induced by Au alloying prevents the strong bonding–antibonding interaction with the antibonding state of the impinging  $O_2$ , resulting in the inertness of the alloy surface.<sup>33,39,40</sup> Moreover, the presence of Au changes the electron distribution (electronic corrugation) on the Cu surface. Thus, one would expect different dynamical processes (e.g., translational to rotational energy transfer effects) occurring when  $O_2$  impinges on a Cu–Au alloy surface as compared to a Cu surface.

In this study, we clarify the alignment dependence of  $O_2$  chemisorption on Cu(110) and Cu<sub>3</sub>Au(110). We do this by using a single-quantum-state-selected (space quantized, following the 1922 Stern-Gerlach experiment<sup>41,42</sup>)  $O_2$  beam developed at NIMS (for which both the molecular alignment and the spin state are well-defined).<sup>10</sup> On Cu(110), as in previous studies, we observed both polar and azimuthal anisotropies.  $O_2$  chemisorption proceeds rather favorably with the O–O bond axis oriented parallel (vs perpendicular)

to the surface and rather favorably with the O–O bond axis oriented along [001] (vs along [110]). O<sub>2</sub> chemisorption on Cu<sub>3</sub>Au(110) shows similar polar and azimuthal anisotropies. However, the presence of Au hinders the surface from further oxidation via a higher activation barrier to chemisorption and an almost negligible azimuthal anisotropy.

#### RESULTS AND DISCUSSION

In Figure 1, we show the measured alignment-dependent O<sub>2</sub> initial sticking probabilities  $(S_0)$  on Cu(110). O<sub>2</sub> in a spin rotational state [(J, M) = (2,2)] exhibit a sin<sup>2</sup>  $\theta$ -dependent O-O bond axis (angular) distribution, where  $\theta$  gives the polar angle subtended by the O–O bond axis with a predetermined defining magnetic field  $(\mathcal{H})$ . Thus, helicopter-like and cartwheel-like rotating O2 (vide ante) can be generated, achieved by directing  $\hat{\mathcal{H}}$  perpendicular or parallel to the surface (Figure 1a). Helicopter-like rotating  $O_2$  have O-Obond axes oriented dominantly parallel to the surface. On the other hand, for cartwheel-like rotating  $O_{2}$ , the O–O bond axes can assume both parallel and perpendicular configurations. We can further prepare two types of cartwheel-like rotating O2 depending on their azimuthal orientation, e.g., by aligning  ${\cal H}$ along [110] (Cartwheel (x),  $C_x$ ) or along [001] (Cartwheel  $(y), C_y$  (see Figure 1a).

In Figure 1b, we show the time evolution of the sticking probability for O<sub>2</sub> on Cu(110), measured while modulating  $\vec{H}$  to alternately produce helicopter-like and cartwheel-like O<sub>2</sub> at  $E_0 = 0.10$  eV. We determined the sticking probability curves by fitting the data points corresponding to each geometry to an exponential decay function (see smooth curves), and the values extrapolated to t = 0 (beam shutter removed) correspond to initial sticking probabilities  $S_0(H)$  and  $S_0(C_y)$ , respectively. Because we are discussing the very early stage of oxidation, Cu segregation<sup>40,43,44</sup> induced by oxygen adsorption need not be considered in  $S_0$ . We see that  $S_0(H) > S_0(C_y)$  and  $S_0(H) >$ 

 $S_0(C_x)$ , in general, indicating that more reactive paralleloriented O<sub>2</sub> as compared to perpendicular-oriented O<sub>2</sub>. This is consistent with previous XPS studies on Cu(111).<sup>45</sup>) From Figure 1b, we can also see from the time evolution of the sticking probabilities that  $S_0(C_x) > S_0(C_y)$ , indicating that O<sub>2</sub> with O–O bond axes oriented along [001] are more reactive than those with O–O bond axes oriented [110].

In Figure 2, we show the corresponding results on  $Cu_3Au(110)$ -(4 × 1). Low-energy electron diffraction



Figure 2. (Space quantized) O<sub>2</sub> sticking probabilities on Cu<sub>3</sub>Au- $(110)-(4 \times 1)$ . (a) LEED patterns for a clean Cu<sub>3</sub>Au(110)-(4 × 1). (b) Schematic depiction of  $Cu_3Au(110)$ -(4 × 1) (Cu, reddish balls; Au, yellowish balls). (c) Time evolution of the sticking probability for a space-quantized O<sub>2</sub> impinging on Cu<sub>3</sub>Au(110)-(4  $\times$  1) (at a surface temperature of ca. 310 K) with translational energy  $E_t = 0.10$  eV. Time t = 0 corresponds to the time the beam shutter is opened to allow the molecular beam to impinge on the surface. Following the control signal shown (topmost right panel), the direction of the defining magnetic field  $\vec{\mathcal{H}}$  can be modulated to alternately produce helicopter-like (high signal) and cartwheel-like (low signal) rotating  $O_2$  that impinge on Cu<sub>2</sub>Au(110)-(4 × 1). Numerical fits to the corresponding sticking probability data points (using exponentially decaying functions extrapolated to t = 0) also shown to guide the eye. The values at t = 0 correspond to the initial sticking probabilities  $S_0(H)$ ,  $S_0(C_x)$ , and  $S_0(C_y)$ .

(LEED) patterns (Figure 2a) indicate Au atom segregation, forming a  $(4 \times 1)$  restructured surface<sup>46</sup> (see Figure 2b). A detailed layer profile of the surface analyses<sup>43</sup> found that 50% of surface Cu atoms on Cu(110) were replaced by Au atoms. This results in a reduction in the O<sub>2</sub> sticking probability to 15% of that on Cu(110). The reduced sticking probability indicates effects from the second-layer Au atoms and/or the nonlocalized contribution of the first-layer Au atoms to the reactive sites. Although we expect the existence of transient molecular states similar to that on Cu(110), the deeper dstates of Au interact weakly with the antibonding states of O<sub>2</sub> without filling them with electrons, rendering it more difficult to form intermediate  $O_2^{\delta-}$  states. Moreover, the expected larger work function of  $Cu_3Au(110)$  compared to Cu(110) (ca. 4.48 eV, and ca. 5.37 eV for Au(110))<sup>47,48</sup> renders negatively charged states unstable. As on Cu(110), we see that  $S_0(H) >$  $S_0(C_y)$  and  $S_0(H) > S_0(C_x)$ , in general. Again, this indicates more reactive parallel-oriented O2 as compared to perpendicular-oriented  $O_2$ . However, in contrast to the case on Cu(110), we find negligible azimuthal anisotropy on  $Cu_3Au(110)$ -(4 × 1), as now we have  $S_0(C_x) \sim S_0(C_y)$ .

To determine how the translational/beam energy  $E_t$  affects the steric effect, in Figure 3a, we plot the ratios  $S_0(H)/S_0(C_x)$ 



**Figure 3.** Translational energy dependence of (space quantized)  $O_2$  initial sticking probabilities on Cu(110) and Cu<sub>3</sub>Au(110). (a) Initial sticking probability ratio  $S_0(H)/S_0(C)$  for helicopter-like and cartwheel-like rotating  $O_2$  on Cu(110) and Cu<sub>3</sub>Au(110) at 310 K. (b) Angular distributions of the  $O_2$  molecular axis (O–O bond axis) oriented perpendicular (along [110]) and parallel (along [110] and [001]) to the corresponding surfaces. (c) Initial sticking probability contributions from the O–O bond axis oriented perpendicular and parallel to Cu(110) and Cu<sub>3</sub>Au(110) as indicated in panel b.

and  $S_0(H)/S_0(C_y)$ , determined from  $S_0(H)$  and  $S_0(C)$  obtained simultaneously by a single modulation measurement, as a function of  $E_t$ . Theoretically, when  $O_2$  with O-O bond axes oriented parallel the surface adsorb, we have  $S_0(H)/S_0(C_x) = 2$ (or  $S_0(H)/S_0(C_y) = 2$ ). And when  $O_2$  can adsorb regardless of O-O bond axes orientations, we have  $S_0(H)/S_0(C_x) = 1$  (or  $S_0(H)/S_0(C_y) = 1$ ). Experimentally, on Cu(110), we find  $S_0(H)/S_0(C_x) = 1.35$  and  $S_0(H)/S_0(C_y) = 1.5$  at  $E_t = 0.10$  eV, and  $S_0(H)/S_0(C_x) \sim S_0(H)/S_0(C_y) \sim 1.0$  for  $E_t \ge 0.33$  eV. This indicates the importance of steric effects at small  $E_t$ becoming negligible for translational/beam energies  $E_t \ge 0.33$ eV. On  $Cu_3Au(110)$ -(4 × 1), the  $E_t$ -dependence of S(H)/S(C)follows a trend similar to that observed on Pt(111),<sup>49</sup> i.e., initial increase in  $S_0(H)/S_0(C_x)$  and  $S_0(H)/S_0(C_y)$  at  $E_t \le 0.26$ eV, and then a gradual decrease from  $E_0 \ge 0.26$  eV.

To determine how the O–O bond axes orientation with respect to the surface normal affects the sticking probability on Cu(110) and Cu<sub>3</sub>Au(110), we plot in Figure 3c the  $E_t$ -

dependent orientation-resolved sticking probabilities  $S_0[001]$ and  $S_0[\overline{1}10]$  for  $O_2$  with O–O bond axes oriented parallel to the surface (along [001] and [ $\overline{1}10$ ], respectively) and  $S_0[110]$ for  $O_2$  with O–O bond axes oriented perpendicular to the surface (along [110]). (For details on how to determine the orientation resolved sticking probabilities, we refer the readers to the Experimental and Theoretical Methods.)

On Cu(110),  $S_0[110]$ ,  $S_0[\overline{110}]$ , and  $S_0[001]$  all increase gradually with increasing  $E_t$  (see Figure 3c). Again, we observe an orientational dependence favoring O–O bond axes oriented parallel to the surface (see  $S_0[\overline{110}] > S_0[110]$  and  $S_0[001] >$  $S_0[110]$  for Cu(110) in Figure 3c). We also observe an inplane azimuthal orientation dependence favoring O–O bond axes oriented parallel to the surface along [001] (see  $S_0[001] >$  $S_0[\overline{110}]$  for Cu(110) in Figure 3c). And, as we have observed earlier, we also see that both polar and azimuthal orientational dependence becomes negligible at  $E_t > 0.3$  eV.

On Cu<sub>3</sub>Au(110)-(4 × 1), we also see that  $S_0[110]$ ,  $S_0[\overline{110}]$ , and  $S_0[001]$  all increase gradually with increasing incident translational (beam) energy (see Figure 3c). Again, we observe an orientational dependence favoring O–O bond axes oriented parallel to the surface (see  $S_0[\overline{110}] > S_0[110]$  and  $S_0[001] >$  $S_0[110]$  for Cu<sub>3</sub>Au(110)-(4 × 1) in Figure 3c), which persists throughout the incident translational (beam) energy range of the experiment, i.e.,  $E_t[eV]$ : [0.1, 0.8]. And, as we have observed earlier, we find negligible in-plane azimuthal orientation dependence.

Upon further examination of the ratios of the corresponding initial sticking probabilities (see Figure 6), we see that the presence of Au considerably decreases the adsorption of  $O_2$ with O–O bond axes oriented perpendicular to the surface (i.e., O–O bond axes parallel to [110]). We also see a negligible effect on the adsorption of  $O_2$  with O–O bond axes oriented parallel to the surface (i.e., O–O bond axes parallel to [001] and [110]).

In the following, we discuss the origin of the different energy dependence of  $S_0$  and its steric effects for Cu(110) and Cu<sub>3</sub>Au(110). As has been shown in the previous study on Cu(110),<sup>24</sup> a barrier exists before  $O_2$  enters the chemisorption well of  $O_2^{\delta-}$ . The magnitude of the barrier depends on the angle of O2 axis relative to the surface plane and on the impact position in the surface unit cell. Molecularly adsorbed  $O_2$  is stable in the geometry with its molecular axis parallel to the surface.<sup>16,19,20</sup> Thus, it is reasonable to expect that the activation barrier to the  $O_2^{\delta-}$  state is lower if  $O_2$  approaches with its molecular axis parallel to the surface. We show that the potential energy curves (PEC) of O2 on Cu(110) manifest such preference (see Figure 4). Moreover, the preferential orientation of  $O_2^{2-}$  is parallel to the [001] direction.<sup>19,20</sup> Therefore, the azimuthal dependence of  $S_0$  appeared at  $E_t \leq 0.20$  eV, possibly revealing the azimuthal dependence of  $O_2^{\delta-}$ stability. Considering bond dissociation, we also plot the potential energy surface (PES) for O<sub>2</sub> in Figure 5. Here, the collisions on the on-top site and the bridge site are not considered because the high activation barrier of such sites cannot be overcome at the experimental incident energy. The adsorption energies of  $O_2$  on Cu(110), at [001] and [110] bond orientations, are -1.82 and -1.66 eV, respectively. Moreover, the activation barrier appears in the entrance channel. By tracing the minimum energy path, we found a relatively higher energy barrier for  $O_2$  dissociation at the  $[\overline{1}10]$ orientation than at the [001] bond orientation on Cu(110). The energy difference between the barriers is about 40 meV.



**Figure 4.** Orientation dependent potential energy curves (PECs) for  $O_2/Cu(110)$ . PECs shown as a function of the  $O_2$  center-of-mass distance Z (Å) above a 4-fold hollow site on Cu(110). PECs calculated with the O–O bond length fixed at a gas phase equilibrium distance of 1.23 Å, and the O–O bond axis orientations fixed parallel to [ $\overline{110}$ ], [001], and [110] on Cu(110). Energies (eV) given with respect to  $O_2$  sufficiently far (ca. 5.0 Å) from Cu(110). Structures and related figures drawn using the VESTA package.<sup>66</sup>

These comparative results agree well with previous calculations on Cu(110).<sup>18,19</sup>  $S_0$  increasing with increasing  $E_t$  can be explained by the widened range of impact parameters at which incident O<sub>2</sub> molecules surmount the barrier. At  $E_t \ge 0.33$  eV,  $S_0(H)/S_0(C) \sim 1.0$  and sticking probability saturates at ~0.65. The lower saturation of sticking probability compared to the previously reported value  $\sim 0.8^{23}$  may be caused by the single rotational state in the beam. On the other hand, the continued  $S_0$  increase upon increasing  $E_t$  could be expected because incident O<sub>2</sub> molecules surmount the higher barrier at the bridge and/or on-top sites, but the saturation of  $S_0$  is different from such expectation. Moreover,  $S_0(H)/S_0(C) \sim 1.0$  at  $E_t \geq$ 0.33 eV indicates no steric preference in O2 sticking. However, the potential landscape and the corresponding energy dissipation process is expected to be quite different for both geometries. To explain the difference between the results and expectation, we speculate the following. The experimental result of  $S_0(H)/S_0(C) \sim 1.0$  suggests the contribution of charge transfer<sup>50,51</sup> into  $O_2^{\delta-}$  state after overcoming the activation barrier at  $E_t \geq \sim 0.4$  eV.<sup>51</sup> The high-energy  $O_2$ comes over the seam between the physisorption state and molecularly adsorbed state. Charge transfer occurs, the shortlived excited  $O_2^{\delta-}$  state couples with substrate excitations, and then de-excited, trapped, and finally O2 dissociates. Although the ground-state interaction potential of  $O_2^{\delta-}$  depends on the alignment of the molecular axis against the surface, the trapping process into the excited  $O_2^{\delta^-}$  state may not strongly depend on the molecular orientation of O<sub>2</sub> because various excited states coupling with the surface are available after the first activation seam into the molecularly adsorbed state is overcome. The steering effects after overcoming the activation barrier also smear out the orientation dependence of charge transfer. The saturation of the sticking probability suggests that the impact condition (location of  $O_2$  and the reaction site at the surface) at which the  $O_2^{\delta-}$  state is stable enough for the dissociative adsorption is limited.

Cu<sub>3</sub>Au(110) has a work function larger than Cu(110).<sup>47</sup> We can thus expect a rather correspondingly less stable  $O_2^{\delta-}$  state. This renders it more difficult for charge transfers to occur, requiring higher  $E_t$  as compared to that on Cu(110). Note that there are more stable molecularly chemisorbed O<sub>2</sub> states on Cu



**Figure 5.** Potential energy surfaces (PESs) for  $O_2$  on Cu(110) and Cu<sub>3</sub>Au(110)-(4 × 1). Potential energy surfaces (PESs) for  $O_2$  and Cu<sub>3</sub>Au(110)-(4 × 1). PESs shown as functions of the  $O_2$  center-of-mass distance Z (Å) (from the 4-fold hollow site (HL) of Cu on Cu(110) (upper panels) and Au on Cu<sub>3</sub>Au(110)-(4 × 1) (lower panels)) and the  $O_2$  bond length  $r_{O-O}$  (Å). PESs calculated with the  $O_2$  bond axis fixed either parallel to [110] (left panels) or parallel to [001] (right panels). Energies (eV) given with respect to  $O_2$  sufficiently far (ca. 5.0 Å) from the surface, in increments of ca. 0.04 eV.

than on Au.<sup>1</sup> Consistent with that, Figure 5 shows an endothermic molecularly adsorbed  $O_2^{\delta^-}$  state, with adsorption energies of 0.10 and 0.12 eV, respectively. The ground state  $O_2$  becomes unstable (ca. > 1 eV) by Au alloying.

The increase in  $S_0(H)/S_0(C)$  at  $E_t \leq 0.26$  eV on  $Cu_3Au(110)$  can be accounted for by the decreasing contribution of the trapping-mediated process in the physisorption well with increasing  $E_t$ . This means that the value of  $S_0(H)/S_0(C)$  for the directly activated process would be higher than the observed value and be close to 2, suggesting that for the direct process to occur at low  $E_t$  conditions, the O-O bond axes must be parallel to the surface. The azimuthal dependence observed on Cu(110) disappears on Cu<sub>3</sub>Au(110) because of the absence of a stable  $O_2^{\delta^-}$  state (see Figure 5). Note that the stability of the  $O_2^{\delta^-}$  depends on its azimuthal orientation on Cu<sub>3</sub>Au(110), and also susceptible to ensemble effect of interaction potentials. The 3% larger lattice constant of Cu<sub>3</sub>Au than Cu renders the active sites for the dissociation of the horizontal molecules practically azimuthally isotropic. The steering effect, which redirects the impinging  $O_2$  to the preferred geometry becomes insufficient at high energies, e.g.,  $E_t > 0.26$  eV. At higher  $E_t$ , O<sub>2</sub> with O–O bond axes oriented perpendicular to the surface can also overcome the activation barrier. The angular distribution of the O-O bond axes could also smear out the steric effect, with the reaction occurring at a finite range of orientations depending on  $E_t$ .

In Figure 6, we show the translational energy dependence of the initial sticking probability ratios  $S_0(Cu_3Au)/S_0(Cu)$  for  $S_0[001]$ ,  $S_0[\overline{110}]$ , and  $S_0[110]$ .  $S_0(Cu_3Au)/S_0(Cu)$  for  $S_0[110]$ exhibits the least value compared to the rest and indicates that Au alloying effectively reduces the sticking of O<sub>2</sub> with O–O bond axes oriented perpendicular to the surface. Au alloying filters the molecular orientation and permeates only O<sub>2</sub> with O–O bond axes oriented horizontal to the surface and supply the O atoms. This filtering effect may lead to the selective



**Figure 6.** Ratios of (space quantized) O<sub>2</sub> initial sticking probabilities on Cu(110) and Cu<sub>3</sub>Au(110). Initial sticking probability ratios for O<sub>2</sub> adsorption on Cu<sub>3</sub>Au(110)-(4 × 1) and Cu(110), with the O–O bond axis oriented along [110], [001], and [110] ( $S_0$ (Cu<sub>3</sub>Au)/ $S_0$ (Cu)[110],  $S_0$ (Cu<sub>3</sub>Au)/ $S_0$ (Cu)[001], and  $S_0$ (Cu<sub>3</sub>Au)/ $S_0$ (Cu)-[110], respectively).

surface chemical reactions and selective oxidative catalytic reactions. Reduction in corrosion of Au alloyed Cu may be attributed to the reduction in the presence (if not complete absence) of intermediate *short-lived*  $O_2^{\delta-}$  that increases reactivity but reduces the steric preference in processes at higher  $E_t$ .

Charge population analyses of adsorbed  $O_2$  on  $Cu_3Au(110)$ and Cu(110) indicate electron gain  $(O_2^{\delta^-} \text{ states}, \text{ see Table 1})$ . Hence, a shallow potential for molecularly chemisorbed  $O_2$  on  $Cu_3Au$  suggests that dissociation via the transiently trapped  $O_2^{\delta^-}$  will be difficult, and the dissociative adsorption may occur over the high adiabatic activation barrier in the

# Table 1. Electron Gain (*e*-Gain) of $O_2$ Adsorbed on $Cu_3Au(110)$ -(4 × 1) and $Cu(110)^a$

surface	O–O bond axis orientated along	O–O bond length (Å)	e-gain (e)
$Cu_3Au(110) - (4 \times 1)$	[001]	1.33	0.61
$Cu_3Au(110)-(4 \times 1)$	[110]	1.43	0.78
Cu(110)	[001]	2.13	1.58
Cu(110)	[110]	2.13	1.72
		1 6 6 5 9	8 ) C

<sup>*a*</sup>e-gain (e) given with respect to  $O_2$  sufficiently far (ca. 5.0 Å) from the corresponding surfaces.

(approximately) usual two-well potential. Unstable molecular chemisorbed  $O_2$  states on  $Cu_3Au$  results in weakened orientation dependence of the  $O_2$  sticking probability. In addition, the large atomic radii of surface Au atoms lessen the anisotropy of the surface charge distribution on  $Cu_3Au(110)$  (see Figure 7). Correspondingly, the electron surface corrugation as seen by an impinging  $O_2$  on Cu(110) varies more between [001] and [110] bond orientations, having a relatively smooth electron surface distribution along the [110] direction or the [001] plane. Collectively, these results confirm the azimuthal dependence of  $O_2$  adsorption on Cu(110) and its inertness toward  $Cu_3Au(110)$ .

# CONCLUSION

In conclusion, we demonstrate the effect of alloying on the steric effects in O<sub>2</sub> dissociative adsorption. At low beam energies, the dissociative adsorption of O2 occurs on the adiabatic potential landscape on Cu(110). O<sub>2</sub> with O–O bond axes parallel to the surface exhibit higher reactivity as compared to those oriented normal to the surface. The reactivity also depends on the O-O bond orientations along the surface. At high beam energies, the O2 in all orientations overcome the activation barrier and steric effects become negligible. Reactions via charge transfer into short-lived  $O_2^{\delta-1}$ state also smear out the steric effects and reduce initial sticking probability saturations to ca. 0.7. On  $Cu_3Au(110)$ , the overall initial sticking probabilities reduce to ca. 15% that of on Cu(110). Except for the negligible azimuthal orientation dependence, the reactivity also shows similar dependence on the O–O bond axes orientations with respect to the surface, as on Cu(110). Alloying with Au increases the activation barrier in the entrance channel, increases the work function, and renders the molecularly chemisorbed  $O_2(O_2^{\delta-})$  state unstable.

#### **EXPERIMENTAL AND THEORETICAL METHODS**

#### **Sample Preparation**

We cleaned the Cu(110) and Cu<sub>3</sub>Au(110) samples by 1.0 eV Ar<sup>+</sup> sputtering and annealing at 773 K. We repeated this procedure until we could no longer detect the impurities by Auger electron spectroscopy (AES).

**Space-Quantized, State-Selected**  $O_2({}^{3}\Sigma^{-}{}_{g})$  **Molecular Beam** For details regarding the experimental apparatus, we refer the readers to previous reports.<sup>10,13</sup> Briefly, we generated  $O_2$  molecular beams by the free expansion of seeded gas of  $O_2/He$ . We then used hexapole magnets to filter the (J, M) state from the  $O_2$  molecular beam. We could also control the translational energy of the state-selected  $O_2(J, M)$  beam by adjusting the number of the hexapole magnets and the  $O_2/He$  mixing ratio of the seeded  $O_2$  beam. Note that we use the following notations:

J = K + S: O<sub>2</sub> total angular momentum with corresponding quantum number *J*;

K:  $O_2$  rotational angular momentum with corresponding quantum number  $K_i$ 

S:  $O_2$  total electron spin angular momentum with corresponding quantum number S;

 $M = M_K + M_S$ : projection of J along the external field direction;

 $M_{K}$  and  $M_{S}$ : projection of **K** and **S** along the external field direction, respectively;

Thus, we are able to prepare  $O_2(J = 2, M = 2)$ , which corresponds to  $O_2(K = 1, M_K = 1, S = 1)$ , with rotational energy  $E_K = BK(K + 1) \approx$ (0.18 meV)(1)(1 + 1) = 0.36 meV, and translational energy  $E_t$ . An  $O_2$ in state ( $K = 1, E_t = 100 \text{ meV}$ ) would have traveled a distance of 15 Å by the time it rotates 90°.

The angular distribution of the  $O_2(J = 2, M = 2)$  molecular axis orientation approximately follows a sin<sup>2</sup>  $\theta$  distribution, where  $\theta$  is the polar angle of the  $O_2$  molecular axis relative to the direction of the defining magnetic field  $\vec{\mathcal{H}}$ . Depending on the orientation of the defining magnetic field  $\vec{\mathcal{H}}$ , i.e., perpendicular or parallel to the surface, we could have helicopter- or cartwheel-like rotating  $O_2(J = 2, M = 2)$ . Helicopter-like rotating  $O_2(J = 2, M = 2)$  have an O–O bond axis oriented parallel to the surface. Cartwheel-like rotating  $O_2(J = 2, M = 2)$  can also have O–O bond axis orientations other than parallel to the surface (i.e., perpendicular and in between). By aligning  $\vec{\mathcal{H}}$ 



Figure 7. Electron distribution on  $Cu_3Au(110)$  and Cu(110). 2D cut through the long bridge (LB) and short bridge (SB) sites of the electron distributions as viewed along [ $\overline{110}$ ] and [001] on the corresponding surfaces. Note the more pronounced orientation-dependent contour difference observed on Cu(110) than on  $Cu_3Au(110)$ -(4 × 1). Electron distributions (e/Å<sup>3</sup>) given with respect to distances sufficiently far (ca. 5.0 Å) from the surface, in increments of 0.005 e/Å<sup>3</sup>.

parallel to  $[\overline{1}10]$  or [001], we can prepare two types of cartwheel-like rotating O<sub>2</sub>, which we label as cartwheels  $C_x$  and  $C_y$ , respectively. Thus, we can prepare a space-quantized, state-selected  $O_2({}^{3}\Sigma^{-}_{g})$  molecular beam, in which nearly all (ca. 100%) of the molecules are in the spin-rotational state (J = 2, M = 2).

Initial Sticking Probabilities for Helicopter-like and Cartwheel-like Rotating  $O_2(J = 2, M = 2)$ 

We express the initial sticking probability  $S_0(H)$  for helicopter-like rotating  $O_2(J = 2, M = 2)$  as<sup>10</sup>

$$S_0(H) = \frac{3}{4\pi} \int_0^{2\pi} \mathrm{d}\phi \int_0^{\pi/2} R_{\mathrm{ave}}(\theta, \phi) \sin^3 \theta \mathrm{d}\theta \tag{1}$$

For the two types of cartwheel-like rotating  $O_2(J = 2, M = 2)$ , viz.,  $S_0(C_x)$  and  $S_0(C_y)$ , we have

$$S_0(C_x) = \frac{3}{4\pi} \int_0^{2\pi} \mathrm{d}\phi \int_0^{\pi/2} R_{\mathrm{ave}}(\theta, \phi) (1 - \sin^2 \theta \sin^2 \phi) \sin \theta \mathrm{d}\theta$$
(2)

and

$$S_0(C_y) = \frac{3}{4\pi} \int_0^{2\pi} \mathrm{d}\phi \int_0^{\pi/2} R_{\mathrm{ave}}(\theta, \phi) (1 - \sin^2 \theta \cos^2 \phi) \sin \theta \mathrm{d}\theta$$
(3)

 $(\theta, \phi)$  give the polar and azimuthal orientation of the O<sub>2</sub> molecular axis with respect to the surface.  $R_{ave}(\theta, \phi)$  gives the reaction rate averaged over the surface unit cell. From eqs 1–3, we then determine the initial sticking probability  $S_0(R)$  for a random distribution, i.e.,

$$S_{0}(R) = \frac{1}{3}S_{0}(H) + \frac{1}{3}S_{0}(C_{x}) + \frac{1}{3}S_{0}(C_{y})$$
$$= \frac{1}{4\pi} \int_{0}^{2\pi} d\phi \int_{0}^{\pi/2} R_{ave}(\theta, \phi) \sin \theta d\theta$$
(4)

For initial sticking probabilities  $S_0[110]$ ,  $S_0[001]$ , and  $S_0[\overline{1}10]$ , which correspond to  $O_2$  with molecular axis parallel to [110], [001], and [ $\overline{1}10$ ], respectively, we have

$$S_{0}[110] = -S_{0}(H) + S_{0}(C_{x}) + S_{0}(C_{y})$$
  
=  $\frac{3}{4\pi} \int_{0}^{2\pi} d\phi \int_{0}^{\pi/2} R_{ave} \cos^{2} \theta \sin \theta d\theta$  (5)

$$S_{0}[001] = S_{0}(H) + S_{0}(C_{x}) - S_{0}(C_{y})$$
  
=  $\frac{3}{4\pi} \int_{0}^{2\pi} d\phi \int_{0}^{\pi/2} R_{ave} \sin^{3}\theta \sin^{2}\phi d\theta$  (6)

$$S_0[\overline{1}10] = S_0(H) - S_0(C_x) + S_0(C_y)$$
  
=  $\frac{3}{4\pi} \int_0^{2\pi} d\phi \int_0^{\pi/2} R_{ave} \sin^3 \theta \cos^2 \phi d\theta$ 

#### **Computational Details**

We performed spin-polarized density functional theory<sup>52,53</sup> (DFT) based total energy calculations,54-57 using the projector augmented wave (PAW) formalism.<sup>58</sup> We employed plane wave basis set, with a cutoff energy of 700 eV. We used the Perdew-Burke-Ernzerhof (PBE) generalized gradient approximation (GGA) for the exchange correlation functional.<sup>59,60</sup> We adopt the Monkhorst and Pack method to perform Brillouin zone integrations, with  $10 \times 10 \times 1$ special k-points,<sup>61</sup> and conduct frozen lattice calculations with energy convergence of less than  $1 \times 10^{-5}$  eV. To model the Cu(110) and Cu<sub>3</sub>Au(110), we used a periodic slab, six atomic layers thick with eight atoms per layer, separated by 15 Å of vacuum along [110]. To obtain the optimized geometry after surface cleaving, we relaxed the first 2 atomic layers of the surface slabs until Hellmann-Feynman forces are less than 0.01 eV/Å. We used a  $(4 \times 2)$  surface unit cell of Cu(110) and  $Cu_3Au(110)$  as the supercell for  $O_2$  adsorption. This takes care of the unwanted interaction between periodic images of O<sub>2</sub>. In the case of Cu<sub>3</sub>Au(111), we adopt the  $(4 \times 1)$  reconstructed

structure for the first two atomic layers. To have a better comparison of the relative strength of adsorption on Au surface atoms of Cu<sub>3</sub>Au(110) and on Cu surface atoms of pristine Cu(110), we chose the 4-fold coordinated Au/Cu hollow site as O<sub>2</sub> adsorption site. We determined the adsorption energies from the change in the total energy of the system with respect to the case with O<sub>2</sub> sufficiently far (ca. 5 Å) from the surface. To determine the charge population of O<sub>2</sub> upon adsorption, we used Bader charge analyses.<sup>62-65</sup> We used the *VESTA* package<sup>66</sup> to draw the structures and related figures.

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#### Notes

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The authors declare no competing financial interest.

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